

UNISONIC TECHNOLOGIES CO., LTD

UD3018

Preliminary

NPN EPITAXIAL SILICON TRANSISTOR

NPN POWER BIPOLAR **TRANSISTORS**

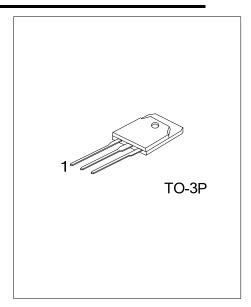
DESCRIPTION

The UTC UD3018 is an NPN transistor. it uses UTC's advanced technology to provide customers with high collector-emitter breakdown voltage and high frequency, etc.

The UTC UD3018 is suitable for professional audio amplifiers and high-end consumer audio products, etc.

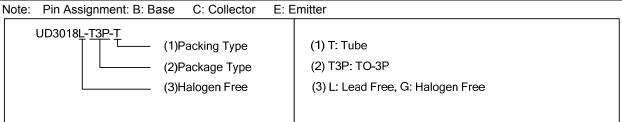
■ FEATURES

- * High collector-emitter breakdown voltage
- * High frequency
- * Excellent gain linearity



ORDERING INFORMATION

Ordering Number		Deelsess	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UD3018L-T3P-T	UD3018G-T3P-T	TO-3P	В	С	Е	Tube	



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	250	V
Collector-Emitter Voltage	V_{CEO}	250	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Collector-Emitter Voltage - 1.5V	V _{CEX}	250	V
Continuous Collector Current		15	Α
Peak Collector Current (Note 1)	Ic	30	Α
Continuous Base Current	I _B	1.5	Α
Total Power Dissipation @ T _C =25°C	P _D	150	W
Operating Junction Temperature	TJ	-65~+150	°C
Storage Temperature Range	T _{STG}	-65~+150	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction-to-Case	$\theta_{ m JC}$	0.83	°C/W

■ ELECTRICAL CHARACTERISTICS (T_C =25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Collector-Emitter Sustaining Voltage	BV _{CEO(SUS)}	I _C =30mA, I _B =0	250			٧
Collector Cut-Off Current	I_{CBO}	V _{CB} =250V, I _E =0			10	μΑ
Emitter Cut-Off Current	I _{EBO}	V _{EB} =5.0V, I _C =0			5.0	μΑ
ON CHARACTERISTICS						
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =5.0A, I _B =0.5A			1.0	V
		I _C =0.5A,V _{CE} =5.0V	75		150	
DC Current Gain	h _{FE}	I _C =1.0A,V _{CE} =5.0V	75		150	
		I _C =3.0A,V _{CE} =5.0V	75		150	
Base-Emitter On Voltage	$V_{BE(on)}$	I _C =5.0A, V _{CE} =5.0V			1.2	V
DYNAMIC CHARACTERISTICS						
Current-Gain-Bandwidth Product	f_{T}	I _C =1.0A, V _{CE} =5.0V, f _{test} =1.0MHz	30			MHz
Output Capacitance	C_{ob}	V _{CB} =10V, I _E =0, f _{test} =1.0MHz			400	pF

^{2.} Pulse Test: Pulse Width=5.0ms, Duty Cycle<10%.

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